



Cite this: *J. Mater. Chem. C*, 2023, **11**, 656

## Ultra-fast low temperature scintillation and X-ray luminescence of CsPbCl<sub>3</sub> crystals

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Halide perovskites recently emerged as promising materials for the detection of ionising radiation. Single crystals of halide perovskites exhibit very fast and bright scintillation when cooled and may outperform the best modern scintillators at temperatures below 100 K. In this work we report on low-temperature scintillation properties of CsPbCl<sub>3</sub> single crystals, grown using the Bridgeman method. The temperature dependences of the luminescence and decay kinetics were studied using X-ray excitation. At low temperatures, the crystal exhibits an intense narrow-band emission at about 420 nm with very fast decay kinetics. This emission, of which a characteristic feature is the strong thermal quenching, is attributed to the radiative decays of bound and trapped excitons. The fast, middle, and slow decay time constants obtained from a fit of a sum of exponential functions to the decay curve at 10 K are 0.1, 1 and 11 ns, respectively. The scintillation light yield of CsPbCl<sub>3</sub> at 7 K measured at excitation with  $\alpha$ -particles from an <sup>241</sup>Am source is estimated to be 140  $\pm$  15% of a reference LYSO-Ce crystal and 19000  $\pm$  2000 ph per MeV under 14 keV X-ray excitation at 10 K. It is concluded that owing to a reduced amplitude of the slow decay component, CsPbCl<sub>3</sub> exhibits an ultra-fast scintillation response that is superior to that of other halide perovskites. The combination of sub-nanosecond response time and the encouraging light yield has the potential of establishing this material as first choice for scintillation applications that rely on prompt detector response at cryogenic temperatures.

Received 31st October 2022,  
Accepted 16th November 2022

DOI: 10.1039/d2tc04631h

rsc.li/materials-c

### 1. Introduction

Scintillation materials with high efficiency and fast response are increasingly important for the detection of ionising radiation. Successful applications of halide perovskites to direct detection of X-rays,<sup>1,2</sup> raised expectations regarding a future role of halide perovskites in high-energy radiation detection,<sup>3</sup> and prompted further studies of their scintillation properties. Lead halide perovskite nanocrystals emerged recently as a potential new generation of scintillating materials that exhibit a high light yield and a very fast decay time.<sup>4–8</sup> Subsequently, recent years witnessed a surge in research activity in this area and many pertinent publications were promptly summarised in a couple of reviews.<sup>9–11</sup> Halide perovskite nanocrystals used for scintillation detection exhibit excellent performance, but there are also

a number of limitations. The exceptional emission characteristics of these nanocrystals, in particular the impressive brightness at room temperature, are due to the favourable combination of two fundamental factors. The first is a quantum confinement effect that prevents thermal quenching and results in a quantum yield of exciton luminescence close to 100%.<sup>12</sup> Second, because of the small dimensions of nanocrystals the near-edge exciton emission has high probability for escaping the volume of the nanocrystal without absorption. It is due to this second factor, that the excellent scintillation properties of these nanoparticles are best put to use when they are prepared as thin ( $\sim$  100  $\mu$ m) films,<sup>4,5,13,14</sup> dispersed in a plastic matrix,<sup>6,15,16</sup> or other crystal hosts.<sup>7,17</sup> However, when it comes to the absorption of ionising radiation this method has a problem. Spectroscopic detection of hard X-rays relies on photoelectric absorption which is a function of absorber composition and thickness. In case of bulk halide perovskites, in order to fully absorb 100 keV X-rays, a material thickness of at least 1 mm is required.<sup>2</sup> This is currently not achievable when using film or dispersed nanocrystals.<sup>18</sup> Therefore, the usefulness of single-crystal scintillators for the detection of high-energy radiation is well-worth investigating.

The concept of applying halide perovskites as scintillation detector of ionising radiation has been discussed since the first observation of the very fast and intense exciton luminescence of

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CsPbX<sub>3</sub> (X = Cl, Br, I) at low temperatures.<sup>19</sup> However, the emission intensity is very temperature dependant due to thermal quenching.<sup>20</sup> The scintillation light yield of CsPbX<sub>3</sub> single crystals is less than 1000 ph per MeV at room temperatures,<sup>21,22</sup> but drastically increases with cooling below 100 K.<sup>23</sup> This temperature range is important for specialised particle physics experiment where the use of cryogenic detectors for ionising radiation facilitates an appreciable enhancement of sensitivity.<sup>24,25</sup> Furthermore, the feasibility of employing fast cryogenic scintillators in nuclear imaging<sup>26</sup> and non-contact thermometry<sup>27</sup> is actively investigated. Thus, taking into account the excellent light yield and very fast decay time observed in halide perovskites at low temperature,<sup>8,23,28</sup> we envisage opportunities for this family of materials in scintillator-based applications at cryogenic temperatures. This motivated us to investigate the X-ray luminescence and scintillation characteristics of CsPbCl<sub>3</sub> from room temperature down to 7 K. The purpose of the study is, by exploring and analysing the temperature dependence of these properties, to assess the potential of the material as cryogenic scintillation detector. Our findings complement recent results for other lead halide perovskites.<sup>8,23,28</sup>

## 2. Methods

The sample of a CsPbCl<sub>3</sub> crystal used in this study was grown by the Bridgeman technique from a stoichiometric mixture of high-purity CsCl and PbCl<sub>2</sub> sealed in a quartz ampoule. Because CsPbCl<sub>3</sub> crystal is only mildly hygroscopic it was cut and polished at ambient conditions. The samples prepared in such way were then kept in sealed jar with silica gel granules and exhibited no visible degradation after storage over more than a year.

Phase and structural characterization of CsPbCl<sub>3</sub> was performed by X-ray powder diffraction (XRD) technique using AERIS benchtop diffractometer (Malvern Panalytical) equipped with PIXcel<sup>1D</sup> strip detector. Experimental diffraction data were collected using filtered Cu K<sub>α</sub> radiation ( $\lambda = 1.54185 \text{ \AA}$ ) in a  $2\theta$  range of 10–105 degrees with a  $2\theta$  step of 0.01°. Crystal structure parameters (unit cell dimensions, coordinates and displacement parameters of atoms) were derived from experimental XRD pattern by full profile Rietveld refinement using WinCSD software package.<sup>29</sup>

The luminescence studies were performed on a freshly polished crystal sample of a volume of  $5 \times 5 \times 4 \text{ mm}^3$ . For X-ray luminescence measurements the sample was placed into a closed-cycle He cryostat, equipped with a DE-202A cryocooler (Advanced Research Systems) and Cryocon 32 (Cryogenic Control Systems Inc.) temperature regulator. The luminescence was excited by a URS-55A X-ray tube with a Cu-anticathode operating at 55 kV and 10 mA. The X-ray beam was entering the cryostat through a beryllium window and irradiated the sample holder placed at 45° to the incoming radiation. The emission was collected in reflection mode through a quartz window of the cryostat. The luminescence spectra were measured using a monochromator MDR-12 and photomultiplier module Hamamatsu H9305.

The decay curves of the crystals were measured at the B16 beamline of Diamond Light Source synchrotron using a 14 keV monochromatic X-ray beam. The measurements were carried out in hybrid mode by triggering on a single X-ray pulse with FWHM of  $\Delta t = 60 \text{ ps}$ , separated from the following pulses by a 300 ns gap. The single crystal, attached to a holder, was placed in a continuous-flow, He-cryostat (Oxford Instruments). The sample temperature was monitored using a Si-diode sensor and stabilised by a PID controller. The X-ray beam with a flux of approx.  $10^9 \text{ ph per (s}\cdot\text{mm}^2)$  was impinging upon the sample placed at 45° to the incoming radiation through a 0.2 mm thick aluminised Mylar window. The luminescence from the illuminated area of  $2 \times 2 \text{ mm}^2$  was collected in reflection mode at 45° through a quartz window. Taking into account the penetration depth of 14 keV X-ray (*ca.* 20  $\mu\text{m}$ ) and absorption coefficient of CsPbCl<sub>3</sub> at the emission peak 420 nm at 10 K (*ca.*  $30 \text{ cm}^{-1}$ )<sup>30</sup> we estimate that in this geometry more than 95% of scintillation light can escape the crystal. The emission was detected using an ID100 single photon counting detector with timing resolution 40 ps sensitive over a 400–900 nm spectral range and a PICO Harp 300 time-correlated single photon counting module.

To measure scintillation properties as function of temperature we used the multiphoton counting technique described in.<sup>31</sup> The sample was attached to the copper sample holder with the <sup>241</sup>Am source placed behind the sample inside a He-flow cryostat. The signal was detected by a multi-alkali photomultiplier model 9124A (Electron Tubes Enterprises). The measurements were carried out while cooling the crystal to eliminate a spurious signal from thermoluminescence.

Density of states (DOS) calculations were carried out using the Quantum-Espresso package.<sup>32</sup> The exchange–correlation functional was chosen in the Perdew–Burke–Ernzerhof generalized gradient approximation, modified for solids with Hubbard correction (GGA-PBESol+*U*). The *U* parameter was selected at 5 eV and applied to Cl p-states. The  $3 \times 3 \times 3$  Monkhorst-Pack mesh was used for the *k*-point sampling of the Brillouin zone of CsPbCl<sub>3</sub>.

## 3. Results and discussion

### 3.1. Crystal structure

Examination of XRD pattern of powdered CsPbCl<sub>3</sub> crystal revealed pure orthorhombic perovskite structure in accordance with ICDD PDF-4 card N 04-024-6243. No traces of impurity phases were detected. Phase purity and crystal structure of the investigated material was further confirmed by full profile Rietveld refinement, performed in space groups *Pnma*. The atomic positions in CsPbCl<sub>3</sub> structure derived from high-resolution X-ray synchrotron powder diffraction<sup>33</sup> were used as a starting model for the refinement. In the refinement procedure, the unit cell dimensions, positions and displacement parameters of atoms and site occupancies were refined together with profile parameters and corrections for instrumental sample shift. As the result, an excellent agreement between experimental and calculated XRD profiles was achieved (see Fig. 1). All the



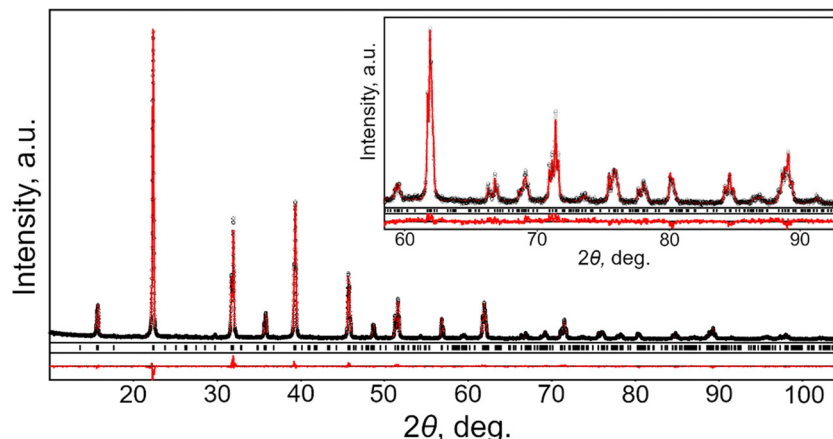


Fig. 1 Graphical results of Rietveld refinement of CsPbCl<sub>3</sub> structures. Experimental XRD pattern (small red circles) is shown in comparison with calculated pattern (black line). Short vertical bars indicate the positions of Bragg's maxima in the orthorhombic perovskite structure. Inset shows enlarged high-angles part of the pattern.

features of experimental powder diffraction pattern of CsPbCl<sub>3</sub> were successfully modelled in space group *Pnma* with the  $\sqrt{2}a_p \times 2a_p \times \sqrt{2}a_p$  metrics of orthorhombic cell. No indications of monoclinic distortion of the structure were observed at room temperature. Obtained structural parameters of CsPbCl<sub>3</sub> and the final residuals are presented in Table 1. Selected interatomic distances and angles in CsPbCl<sub>3</sub> structure derived from the refined values of the lattice parameters and atomic coordinates are collated in Table 2.

The results obtained in the present study prove orthorhombic GdFeO<sub>3</sub>-type of perovskite structure of CsPbCl<sub>3</sub>, being in agreements with abovementioned comprehensive examination of this material,<sup>33</sup> as well as with the recent temperature-dependent high resolution synchrotron powder diffraction investigations in the temperature range 90–823 K.<sup>34</sup> According to the latter study, CsPbCl<sub>3</sub> undergoes two successive phase transitions from ideal cubic *Pm3m* perovskite to tetragonal *P4/mbm* structure at 325 K and finally to orthorhombic *Pbnm* (*Pnma*) structure at 316 K.

Room temperature structure of CsPbCl<sub>3</sub> belongs to the most widespread family of ABO<sub>3</sub> perovskite structures, namely GdFeO<sub>3</sub>-type, which is characterised by anti-phase tilting of the corner-shared BO<sub>6</sub> octahedra according to Glazer tilt system  $a^-b^+a^-$ . Magnitudes of octahedra tilt angles about the cubic [001] and [110] axes can be estimated from the deviation of Pb–Cl1–Pb and Pb–Cl2–Pb bond angles (Table 2) from 180°, respectively. The PbCl<sub>6</sub> octahedra in CsPbCl<sub>3</sub> structure are slightly distorted due to the deviation of the Pb–Cl distances

Table 2 Selected interatomic distances in CsPbCl<sub>3</sub> structure

Atoms	Distances, Å	Atoms	Distances, Å	Atoms	Angles, deg.
Cs–Cl1 × 2	3.488(10)	Pb–Cl1 × 2	2.787(13)	Pb–Cl1–Pb	160.08(4)
Cs–Cl2	3.580(10)	Pb–Cl2 × 2	2.839(2)	Pb–Cl2–Pb	164.06(4)
Cs–Cl2	3.806(14)	Pb–Cl1 × 2	2.883(12)		
Cs–Cl2 × 2	3.885(10)	Pb–Cl(ave)	2.836		
Cs–Cl2 × 2	4.062(11)				
Cs–Cl1	4.126(14)				
Cs–Cl1	4.333(10)				
Cs–Cl2 × 2	4.474(11)				

from the average value of 2.836 Å (Table 2) and Cl–Pb–Cl bond angles (not shown here) inside octahedra from 90°. The distorted cubooctahedral holes in CsPbCl<sub>3</sub> structure are occupied by cesium ions. Distribution of Cs–Cl distances inside CsCl<sub>12</sub> polyhedra is non-uniform: two shortest Cl atoms are located at the distance of 3.488 Å from the central Cs atom, whereas two remote Cl species lie at the distance of 4.474 Å (Table 2).

### 3.2. X-ray luminescence

Emission properties of CsPbCl<sub>3</sub> are known to be very sensitive to the temperature, and that is clearly manifested in X-ray luminescence spectra of the crystal (see Fig. 2). X-ray excitation of the crystals at 10 K reveals a structured luminescence spectrum with two narrow peaks at 417 nm (1) and 421 nm (2) with a broad shoulder (3) on the low-energy side of the

Table 1 Lattice parameters, coordinates and displacement parameters of atoms in CsPbCl<sub>3</sub> structure at room temperature (space group *Pnma*, *Z* = 4)

Lattice parameters, residuals	Atoms, sites	<i>x/a</i>	<i>y/b</i>	<i>z/c</i>	<i>B</i> <sub>iso/eq</sub> , Å <sup>2</sup>	Occupancy
<i>a</i> = 7.8994(3) Å	Cs, 4c	0.5042(5)	$\frac{1}{4}$	0.0039(9)	4.16(4)	0.995(5) Cs <sup>+</sup>
<i>b</i> = 11.2459(2) Å	Pb, 4a	0	0	0	0.40(2)	1.002(5) Pb <sup>2+</sup>
<i>c</i> = 7.8960(3) Å	Cl1, 4c	−0.0435(13)	$\frac{1}{4}$	−0.024(2)	1.9(2)	1.01(1) Cl <sup>−</sup>
	Cl2, 8d	0.209(2)	−0.0232(5)	0.717(2)	1.54(14)	1.03(2) Cl <sup>−</sup>

$$R_1 = 0.038, R_p = 0.090$$



spectra. The measured X-ray luminescence spectrum exhibits a pronounced change with temperature. The overall emission intensity decreases with heating due to non-radiative quenching processes. The narrow peak 1 is manifest only at low temperatures and its position in energy at 2.97 eV is very close to the low-temperature exciton absorption of CsPbCl<sub>3</sub>. The position of this peak agrees with the published data on photoluminescence of bulk crystals,<sup>19,20,35</sup> microcrystals and films,<sup>36,37</sup> of CsPbCl<sub>3</sub>. It should be noted, however, that in nanocrystals this peak is shifted towards higher energy,<sup>38,39</sup> similar to what is observed in other inorganic halide perovskites.<sup>40</sup> This emission peak is commonly attributed to the recombination of bound excitons. There is also consensus in the literature on the interpretation of the emission emerging with cooling at the low-energy side of the luminescence spectra of lead-based perovskites (shoulder 3). It is assigned to the radiative recombination of trapped excitons.<sup>20,23,28,35,40</sup> The low-energy peak 2 has been reported only in a few luminescence studies of CsPbCl<sub>3</sub> bulk crystals.<sup>19,35</sup> Similarly, the structured luminescence has been observed in CsPbBr<sub>3</sub> and there is extensive discussion regarding its origin. Although the exact nature of the band remains unclear, the most plausible explanations are self-trapped exciton,<sup>41</sup> re-absorption effect,<sup>42</sup> bulk vs surface recombination<sup>43</sup> and Rashba-splitting.<sup>44</sup>

Another interesting feature of the X-ray luminescence of CsPbCl<sub>3</sub> crystals is the abnormal shift of the main emission bands with temperature as shown in the insert of Fig. 2. Both emission bands exhibit a blue shift with rising temperature. The intensity of peak 1 decreases and it amalgamates with peak 2 above 50 K. The band formed by merging continues to shift towards the blue with heating until temperature reaches 100 K. Above that, the emission band exhibits a steady spectral shift towards the red with increasing temperature. A similar behaviour of the emission bands has been previously observed in CsPbBr<sub>3</sub>.<sup>28</sup>

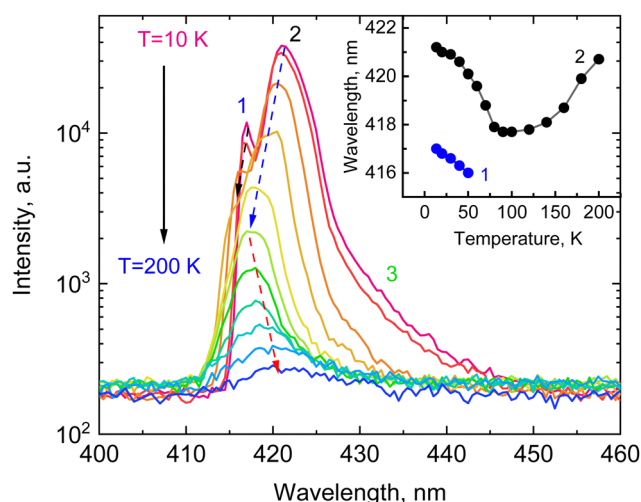


Fig. 2 X-ray luminescence spectra of a CsPbCl<sub>3</sub> crystal measured at different temperatures displayed in logarithmic scale. Dashed arrows show the direction of shift for peaks 1 and 2 with temperature. The insert shows the shift of emission peaks 1 and 2 as a function of temperature.

The temperature shift of the edge emission of semiconductors correlates with the temperature evolution of the band gap that is mainly due to electron–phonon interaction. It causes changes in the band structure due to lattice vibrations resulting in a decrease of the band gap with increasing temperature.<sup>45</sup> The thermal expansion of the lattice is considered as a second factor that contributes to these changes. It can cause either a decrease or an increase of the band gap depending on the detailed structure of the valence and conduction bands. Studies of the temperature-dependent luminescence of perovskites reveal that thermal expansion with heating is a main factor that controls the position of the band gap at low temperatures.<sup>46,47</sup> The valence band maximum of lead-halide perovskites is formed by hybridisation of states of Pb and halide ions.<sup>48,49</sup>

To elucidate the origin of the top of the valence band (VB) and the bottom of the (CB) in CsPbCl<sub>3</sub>, we carried out first-principles calculations using density functional theory. The DOS and PDOS for CsPbCl<sub>3</sub> in the low-temperature orthorhombic phase are plotted in Fig. 3. The core Cs ion p-states, which form narrow bands located deep at about −10.9 eV have almost no effect on the VB or CB. The hybridized Pb s-states, and the Cl s-states can be observed deep on the energy scale between −13.8 and −7.8 eV. The top of the VB is mainly formed by Cl p-orbitals with smaller contribution of Pb s- and p-orbitals while the bottom of the conduction band is predominantly formed by hybridized p-states of lead. Cs p-orbitals and Cl p-orbitals contribute to the upper part of the CB. Thermal expansion of the crystal lattice with an increase of temperature may weaken the interaction between these states, leading to a reduction of the width of the valence band and an increase of the forbidden band gap. This causes a blue shift of the edge emission, which is consistent with the high-energy shift of the exciton band observed in the reflection spectra of CsPbCl<sub>3</sub> crystals.<sup>50</sup> However, as the temperature rises the electron–phonon interaction starts to dominate, leading to a decrease of the band gap and a red shift of the emission band. Such behaviour of the band gap can explain the observed temperature shift of the CsPbCl<sub>3</sub> emission bands.

### 3.3. Dynamics of X-ray excited emission with temperature

The dynamic of the radiative decay of X-ray emission was investigated over the low-temperature range by using pulsed excitation at a synchrotron source. Fig. 4a illustrates the temperature evolution of decay curves of the CsPbCl<sub>3</sub> crystal, measured for excitation by monochromatic X-rays with an energy of 14 keV. The decay curves recorded for the entire emission spectrum of the sample exhibit very fast, non-exponential kinetics. This is due to contributions from different recombination processes and emission centers that is a typical feature of lead-based halide perovskites. The decay kinetics experiences significant changes in shape with decrease of temperature: the peak intensity promptly increases; the long decay component emerges at ca. 90 K and its contribution continues to increase at cooling.

To facilitate quantitative analysis of the measured decay curves they were fitted with a sum of exponential functions:  $f(t) = \sum_i A_i \exp(-t/\tau_i) + y_0$ , where  $A_i$  is the amplitude,  $\tau_i$  the





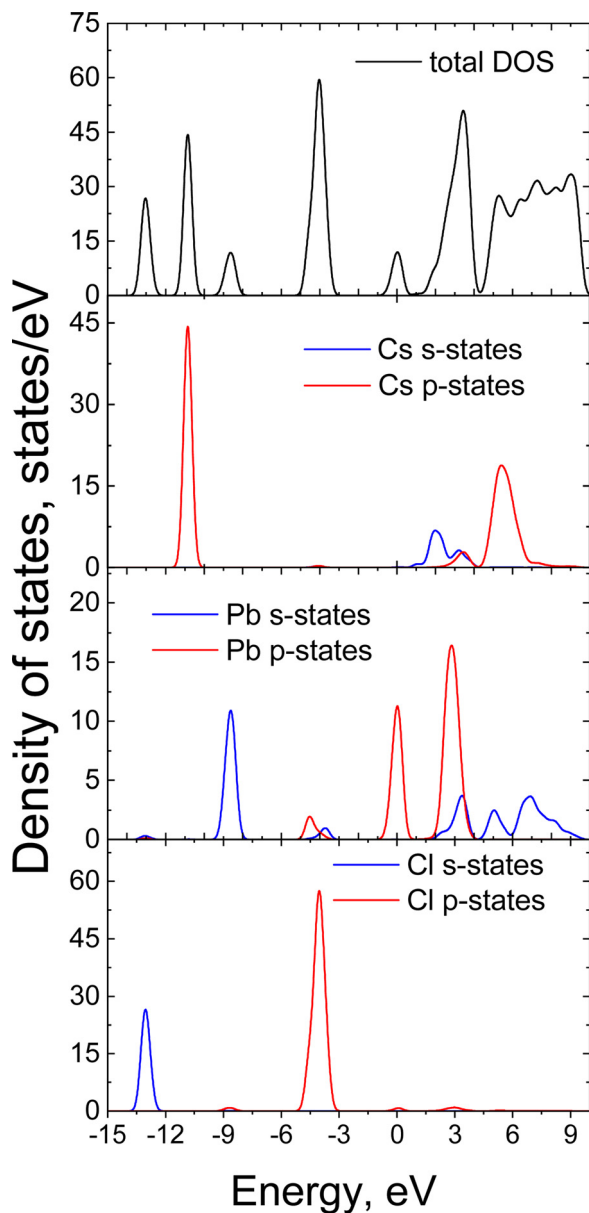


Fig. 3 The DOS and PDOS calculated using the GGA-PBEsol+*U* functional for orthorhombic CsPbCl<sub>3</sub>.

decay time constant and  $y_0$  the background. It should be noted that the multi-exponential fit is widely applied to quantify the processes of recombination decay in semiconductors. Two exponents provided adequate fitting at  $T > 90$  K while to account for the occurrence of the slow emission component at lower temperatures we introduced a third component resulting in *R*-square better than 0.99. The parameters derived from the fit are summarized in Fig. 5a and b. The amplitudes of  $A_1$ ,  $A_2$  and  $y_0$  exhibit a similar trend; they all decrease as the temperature rises. The third component ( $A_3$ ) provides a considerable contribution to the decay kinetics of CsPbCl<sub>3</sub> at 40 K, while its amplitude rapidly reduces at lower and higher temperatures. Notably, this correlates with the temperature changes of the slow decay component amplitude observed recently in the study of luminescence kinetics of CsPbBr<sub>3</sub>.<sup>28</sup>



Fig. 4 (a) Decay curves of X-ray luminescence measured in the CsPbCl<sub>3</sub> crystal as temperature reduced down to 10 K. The luminescence is excited by X-ray pulses of synchrotron radiation ( $E = 14$  keV). (b) Comparison of decay curves of CsPbCl<sub>3</sub> and CsPbBr<sub>3</sub> crystals measured at 10 K under the same experimental conditions. The red lines show the fit of experimental data by a sum of exponential functions.

Analysis of these results demonstrates that CsPbCl<sub>3</sub> exhibits much faster decay kinetics in comparison with other cesium lead halides.<sup>39,51</sup> This is clearly seen from the juxtaposition of the decay curves of the two crystals displayed in Fig. 4b. The measured fast decay constant  $\tau_1$  is *ca.* 0.1 ns which is one order of magnitude less than what has been found in the X-ray luminescence kinetics of CsPbBr<sub>3</sub>.<sup>28</sup> This value is also consistent with the decay time constant reported in recent studies of the luminescence kinetics of CsPbCl<sub>3</sub> microcrystals.<sup>37</sup> Two other decay constants  $\tau_2$  and  $\tau_3$  derived from the fitting are about one and two order of magnitude larger. As can be seen from Fig. 5a, all decay time constants decrease with rising temperature. It should be noted that this behavior is different from what is typically reported for nanocrystals where the short decay component increases with rising temperature while the slow one decreases.<sup>39,41,52,53</sup>

In line with previous studies, we attribute the fast ( $\tau_1$ ) and middle ( $\tau_2$ ) components in the emission of CsPbCl<sub>3</sub> to the radiative decay of bound excitons. The delayed component  $\tau_3$



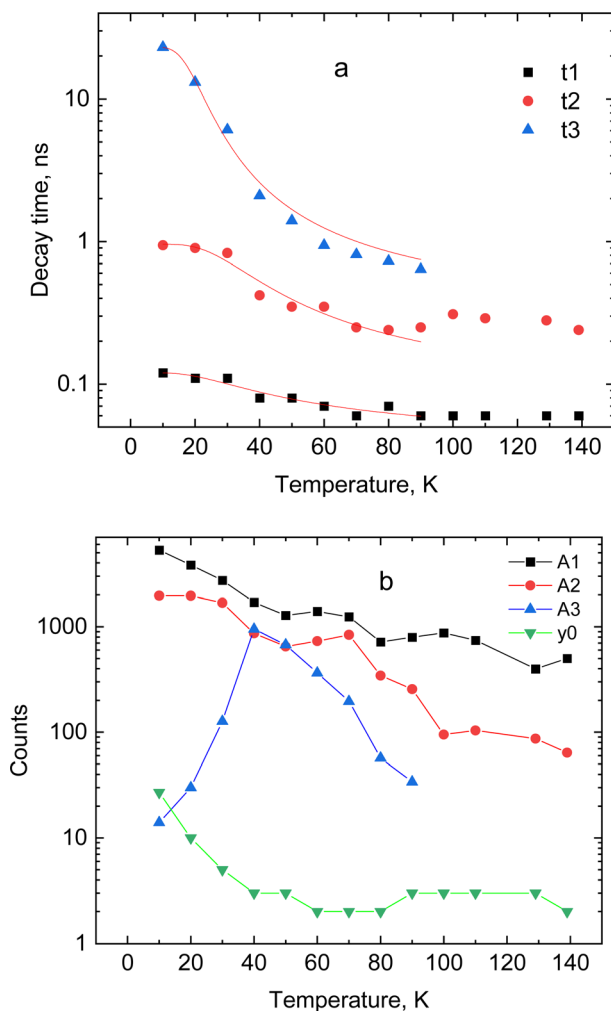


Fig. 5 Temperature dependence of decay constants (a) and amplitudes with background (b) obtained from the fitting of decay curves for CsPbCl<sub>3</sub> using a sum of exponential functions: the lines in (a) show the best fit to the temperature dependence of the decay constant  $\tau_i = f(T)$  using the model of thermally activated transitions (eqn (1)).

with decay time  $\sim 1$  ns appears because of formation of bound excitons released from shallow trap states.<sup>28,40</sup> The slow emission component ( $\tau_3$ ), observed below 80 K, is assigned to the radiative recombination of the trapped excitons. This is a thermally activated process and, subsequently, the emission is very slow at low temperature: it mostly contributes to the background at very low temperatures but with increasing temperature this component starts to emerge in the decay curve. The amplitude of this component gradually increases until the onset of the non-radiative quenching. This behaviour of the slow decay is consistent with the changes in the amplitude of this component with temperature, mentioned above.

The observed temperature dependences of the decay rates are very typical for an emission that is governed by processes of thermally activated depopulation of excited states. As the temperature increases the bound and trapped excitons can be released, captured by traps, and subsequently decay non-radiatively. The process of such thermally driven changes can

be quantified through a simple model that expresses the relationship between the decay rate and temperature as:

$$\frac{1}{\tau_i} = \frac{1}{\tau_{0i}} + K_i \exp\left(-\frac{\Delta E_i}{kT}\right), \quad (1)$$

where  $\tau_{0i}$  is the luminescence decay time constant at  $T = 0$  K,  $K_i$  is the deactivation rate,  $\Delta E_i$  is the thermal activation energy for the process in question,  $k$  is Boltzmann's constant and  $i = 1, 2$  and  $3$ . The fit of the data displayed in Fig. 5a yields values of  $K_i \sim 10^9$ – $10^{10}$  s<sup>-1</sup> and  $\Delta E$  in the 6–10 meV range, suggesting efficient delocalization and de-trapping of excitons even at low temperatures. As the temperature increases the excitons can delocalize or escape the traps and start migrating across the crystal until they reach a quenching centre and decay non-radiatively.

### 3.4. Low temperature scintillation properties

The results for CsPbCl<sub>3</sub> demonstrated that at low temperatures the crystal exhibits a bright and very prompt luminescence response under X-ray excitation thus satisfying two key attributes of a scintillator. To assess the potential of this material for the detection of ionizing radiation we measured the light output for excitation with alpha particles. The pulse height spectrum of CsPbCl<sub>3</sub> shown in Fig. 6a features a well-resolved peak, caused by 5.49 MeV  $\alpha$ -particles from an <sup>241</sup>Am source depositing their kinetic energy in the crystal. The peak position is proportional to the light output of the crystal, allowing a study of the variation of scintillation light yield with temperature.<sup>31</sup> Fig. 6b shows that the scintillation efficiency of CsPbCl<sub>3</sub> remains roughly constant for temperatures below ca 50 K and above that it decreases with heating. Such behaviour of the light yield as a function of temperature is a common feature observed for the majority of undoped scintillators, and is explained by the thermal quenching effect.<sup>54</sup> The temperature dependence of scintillation light output can be fitted by the classic Mott formula:

$$I = I_0 / \left(1 + K \exp\left(-\frac{E}{kT}\right)\right), \quad (2)$$

where  $I_0$  is the initial luminescence intensity,  $K$  is a constant,  $E$  is the thermal activation energy of the thermal quenching process,  $k$  is Boltzmann's constant. Fitting the  $I = f(T)$  plot with eqn (2) gave a value of  $34 \pm 1$  meV for the characteristic activation energy of non-radiative thermal quenching in CsPbCl<sub>3</sub>.

Theoretical estimates of the scintillation efficiency of CsPbCl<sub>3</sub> carried out using a semi-empirical approach<sup>54</sup> gave an upper limit for the absolute light yield of 81300 ph per MeV. The light yield was calculated using the following equation:

$$LY = \frac{10^6}{2.35E_g} \left[ 1 + 0.158 \times 10^4 \left\{ \frac{1}{\epsilon_\infty} - \frac{1}{\epsilon_{\text{stat}}} \right\} \frac{(h\nu_{\text{LO}})^2}{1.5E_g} \right]^{-1} \quad (\text{ph per MeV}) \quad (3)$$

Here  $E_g = 3.05$  eV is the band gap energy of CsPbCl<sub>3</sub>,<sup>39</sup>  $\epsilon_{\text{stat}} = 15.7$  and  $\epsilon_\infty = 3.7^{55}$  are the static and high-frequency relative permittivity,  $h\nu_{\text{LO}} = 46$  meV<sup>56</sup> is the maximum energy of LO



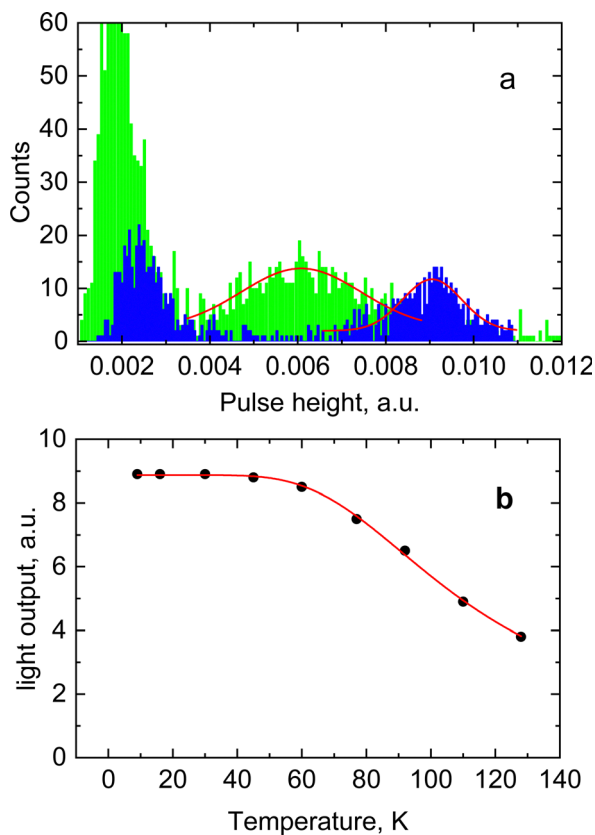


Fig. 6 (a) Pulse height spectra of scintillations caused by  $\alpha$ -particles (5.5 MeV) from a  $^{241}\text{Am}$  source with  $\text{CsPbCl}_3$  at 7 K (blue) and  $\text{LYSO-Ce}$  (green) at 295 K. The red line shows the fitting of a Gaussian to the peak that is attributed to  $\alpha$ -particle interaction. The rise of the signal near the origin is due to the detector threshold. (b) The light output of  $\text{CsPbCl}_3$  as function of temperature for  $\alpha$ -particle excitation. The red line shows the best fit of the temperature dependence using the model of thermally activated transitions.

phonons. The scintillation light yield was determined experimentally by comparing the pulse height spectrum of  $\text{CsPbCl}_3$  displayed in Fig. 5a with data from a reference  $\text{LYSO-Ce}$  scintillator. The light yield was obtained assuming that the light collection efficiency is the same for both crystals. Under such assumption the light yield of an unknown crystal can be derived by comparing with a reference scintillator after correction for different spectral sensitivity of the photodetector.<sup>57</sup> From these measurements we estimated that at excitation with  $\alpha$ -particles the relative light output of  $\text{CsPbCl}_3$  at 7 K is equal to  $140 \pm 15\%$  of  $\text{LYSO-Ce}$ .

Another estimate of the scintillation light yield can be done by integrating area under the scintillation decay curve detected at pulsed X-ray excitation following the approach that has been suggested by<sup>59</sup> and later tested in ref. 28. The recorded sequences of scintillation pulses from  $\text{CsPbCl}_3$  and  $\text{LYSO-Ce}$  excited by X-rays from synchrotron was integrated over time interval of 20 ns. After correction for the spectral response of the detector and taking into account the absolute light yield of  $\text{LYSO-Ce}$  equal to 34 000 ph per  $\text{MeV}$ <sup>58</sup> and non-proportionality of the scintillator (55% at 14 keV<sup>60</sup>) the light yield of  $\text{CsPbCl}_3$

under 14 keV X-ray excitation was found to be  $19\,000 \pm 2000$  ph per  $\text{MeV}$  at 10 K.

The obtained values are more than factor two less than the light yield measured by us in bromide perovskites.<sup>8,28</sup> Note, however, that in  $\text{CsPbBr}_3$  the very slow component seen as a constant background in the decay curves has much higher amplitude and hence a significant contribution to scintillation. Such a feature is very clearly visible in Fig. 3b. Furthermore, in  $\text{CsPbCl}_3$  the intensity of the long-wavelength band attributed to the slow recombination luminescence is notably reduced in comparison with  $\text{CsPbBr}_3$ . The reduced contribution from the slow recombination emission is likely to cause a decrease of the total scintillation light yield of the  $\text{CsPbCl}_3$  crystal. Crucially, a decrease of the slow component is always beneficial from the viewpoint of practical applications of scintillators as this allows a reduction of pile-up and facilitates fast counting. Overall, an estimate of the initial photon density calculated as a ratio of light yield to effective decay time constant shows that in  $\text{CsPbCl}_3$  this parameter is compatible with those observed in other perovskites at low temperatures.

## 4. Conclusion

In summary, we studied the scintillation and luminescence properties of a  $\text{CsPbCl}_3$  single crystal as function of temperature using X-rays and particle excitation. It has been found that at low temperature the crystal exhibits an intense narrow-band blue emission due to the radiative decay of bound and trapped excitons. The emission is very sensitive to temperature and quenches at higher temperatures. The scintillation light yield for excitation with  $\alpha$ -particles from an  $^{241}\text{Am}$  source was estimated to be equal to  $140 \pm 15\%$  of  $\text{LYSO-Ce}$  at 7 K. Studies of the luminescence kinetics of  $\text{CsPbCl}_3$  with pulsed X-ray excitation from a synchrotron showed that the crystal exhibits a very fast decay component at low temperatures. In contrast to bromide perovskites, the decay curves of  $\text{CsPbCl}_3$  show a small contribution of a very slow decay component which is due to recombination processes. These findings evidence that the crystal is excellent for applications that rely on fast scintillation response at cryogenic temperatures.

## Author contributions

V. B. M. instigated the idea of the study, A. V. and Y. C. provided the crystal samples, H. K. designed electronic and software for scintillation detection, V. B. M. designed and supervised the experiments and analysed the results, N. V. assisted in setting up the experiment at synchrotron, V. B. M., V. K. and M. R. conducted the measurements, L. V. measured and analysed XRD data, V. K. carried out theoretical modelling, V. B. M. drafted the manuscript, H. K. and V. B. M. edited the manuscript. All authors contributed to the manuscript revision.

## Conflicts of interest

There are no conflicts of interest to declare.



## Acknowledgements

The work was partially supported by the Ministry of Education and Science of Ukraine. Measurements at B16 beamline of Diamond Light Source were supported through the proposal NT31228.

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